















**ESD** 

TVS

MOS

LDO

Diode

Sensor

DC-DC

# **Product Specification**

Domestic Part Number	ESD9N12BA
Overseas Part Number	ESD9N12BA
▶ Equivalent Part Number	ESD9N12BA



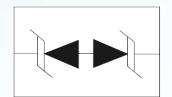


#### **Descriptions**

ESD9N12BA The **TVS** (Transient Voltage is protect Suppressor) designed to sensitive electronic which are components connected data and to transmission lines from over-stress caused by ESD (Electrostatic Discharge), EFT (Electrical Fast Transients) and lightning.

The ESD9N12BA may be used to provide ESD protection up to ±30kV (contact discharge) according to IEC61000-4-2, and withstand peak pulse current up to 5.5A (8/20µs) according to IEC61000-4-5.

The ESD9N12BA is available in DFN1006-2L package. Standard products are Pb-free and Halogen-free.



#### **Features**

- Stand-off voltage: ±12V Max.
- Transient protection for each line according to IEC61000-4-2 (ESD): ±30kV (contact discharge) IEC61000-4-5 (surge): 5.5A (8/20µs)
- Capacitance:  $C_J = 27pF$  typ.
- Ultra-low leakage current: I<sub>R</sub> = 0.1nA typ.

  Low clamping voltage: V<sub>CL</sub> = 20V typ. @ I<sub>PP</sub> = 16A (TLP)
- Solid-state silicon technology

#### **Applications**

- Computers and peripherals
- Cellular handsets
- Portable Electronics
- Notebooks

**Absolute maximum ratings** 

Parameter	Symbol	Rating	Unit	
Peak pulse power (t <sub>p</sub> = 8/20µs)	P <sub>pk</sub>	99	W	
Peak pulse current (t <sub>p</sub> = 8/20µs)	· I <sub>PP</sub>	5.5	А	
ESD according to IEC61000-4-2 air discharge	V	±30	kV	
ESD according to IEC61000-4-2 contact discharge	- V <sub>ESD</sub>	±30		
Junction temperature	TJ	125	°C	
Operating temperature	T <sub>OP</sub>	-40~85	°C	
Lead temperature	TL	260	°C	
Storage temperature	T <sub>STG</sub>	-55~150	°C	

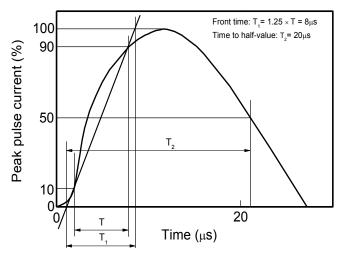


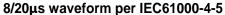
#### Electrical characteristics (T<sub>A</sub>=25 °C, unless otherwise noted)

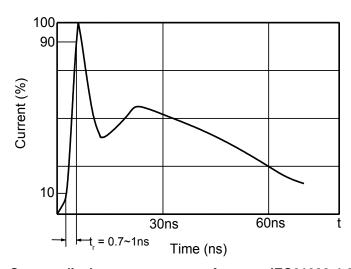
Parameter	Symbol	Condition	Min.	Тур.	Max.	Unit
Stand-off voltage	$V_{RWM}$				±12	V
Reverse leakage current	I <sub>R</sub> V <sub>RWM</sub> = 12V			0.1	50	nA
Reverse breakdown voltage	$V_{BR}$ $I_{T} = 1mA$		13		16.5	V
Clamping voltage 1)	V <sub>CL</sub>	$I_{PP} = 16A, t_p = 100ns$		20		V
Dynamic resistance 1)	R <sub>DYN</sub>			0.35		Ω
Clamping voltage <sup>2)</sup>	V <sub>CL</sub>	$I_{PP} = 1A, t_p = 8/20 \mu s$			16	V
Clamping voltage		$I_{PP} = 5.5A, t_p = 8/20 \mu s$			18	V
lunction consoitence	CJ	V <sub>R</sub> = 0V, f = 1MHz		27	35	pF
Junction capacitance		V <sub>R</sub> = 12V, f = 1MHz		14	20	pF

<sup>1)</sup> TLP parameter:  $Z_0 = 50\Omega$ ,  $t_p = 100$ ns,  $t_r = 2$ ns, averaging window from 60ns to 80ns.  $R_{DYN}$  is calculated from 4A to 16A.

### Typical characteristics (T<sub>A</sub>=25°C, unless otherwise noted)





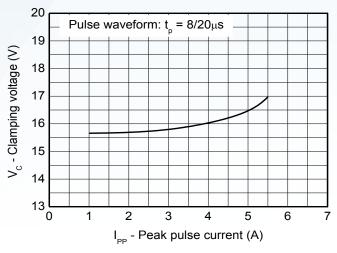


Contact discharge current waveform per IEC61000-4-2

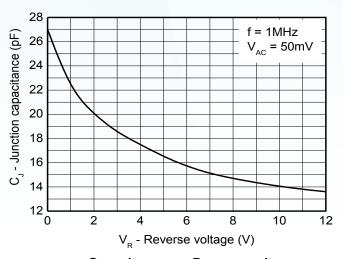
<sup>2)</sup> Non-repetitive current pulse, according to IEC61000-4-5.



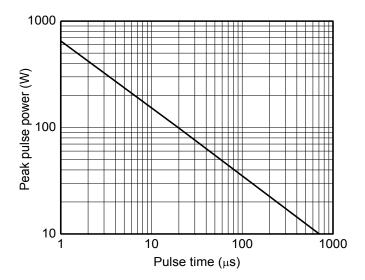
## Typical characteristics (T<sub>A</sub>=25°C, unless otherwise noted)

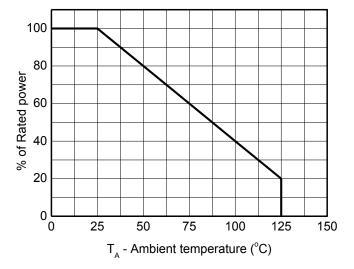


Clamping voltage vs. Peak pulse current



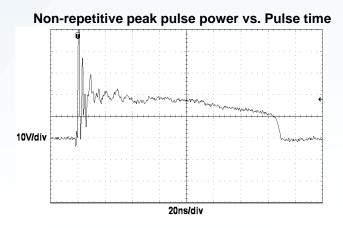
Capacitance vs. Reverse voltage



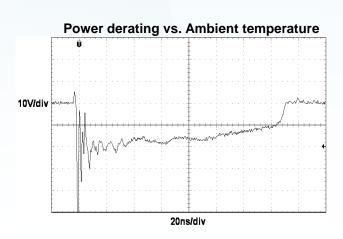




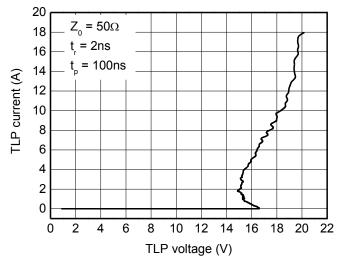
#### Typical characteristics (T<sub>A</sub>=25°C, unless otherwise noted)



ESD clamping (+8kV contact discharge per IEC61000-4-2)



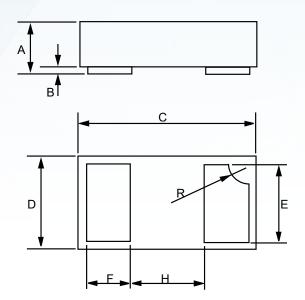
ESD clamping (-8kV contact discharge per IEC61000-4-2)



**TLP Measurement** 



#### **DFN1006-2 PACKAGE OUTLINE DIMENSIONS**



Dim	Inc	hes	Millimeters		
	MIN	MAX	MIN	MAX	
Α	0.013	0.020	0.34	0.50	
В	0.000	0.002	0.00	0.05	
С	0.037	0.042	0.95	1.075	
D	0.021	0.026	0.55	0.675	
Е	0.017	0.021	0.45	0.55	
F	0.007	0.011	0.20	0.30	
Н	0.015Typ.		0.40Тур.		
R	0.001	0.005	0.05	0.15	

# Marking



# **Ordering information**

Order code	Package	Baseqty	Deliverymode
ESD9N12BA	DFN1006-2	10000	Tape and reel



# Disclaimer

EVVOSEMI ("EVVO") reserves the right to make corrections, enhancements, improvements, and other changes to its products and services at any time, and to discontinue any product or service without notice.

EVVO warrants the performance of its hardware products to the specifications applicable at the time of sale in accordance with its standard warranty. Testing and other quality control techniques are used as deemed necessary by EVVO to support this warranty. Except where mandated by government requirements, testing of all parameters of each product is not necessarily performed.

Customers should obtain and confirm the latest product information and specifications before final design, purchase, or use. EVVO makes no warranty, representation, or guarantee regarding the suitability of its products for any particular purpose, nor does EVVO assume any liability for application assistance or customer product design. EVVO does not warrant or accept any liability for products that are purchased or used for any unintended or unauthorized application.

EVVO products are not authorized for use as critical components in life support devices or systems without the express written approval of EVVOSEMI.

The EVVO logo and EVVOSEMI are trademarks of EVVOSEMI or its subsidiaries in relevant jurisdictions. EVVO reserves the right to make changes without further notice to any products herein.